

# RJP5001APP-M0

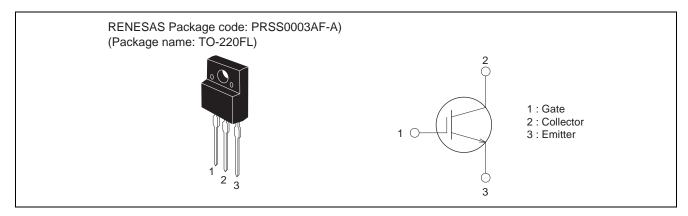
## Nch IGBT for Strobe Flash

R07DS0750EJ0100 Rev.1.00 Apr 26, 2012

#### **Features**

- V<sub>CES</sub>: 500 V
- TO-220FL package
- High Speed Switching

#### **Outline**



### **Applications**

Strobe flash

## **Maximum Ratings**

 $(Tc = 25^{\circ}C)$ 

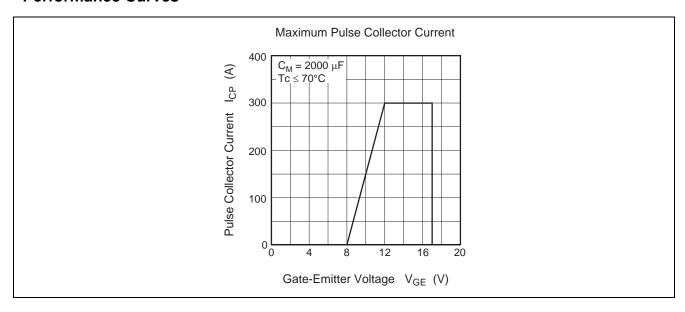
Parameter	Symbol	Ratings	Unit	Conditions
Collector-emitter voltage	V <sub>CES</sub>	500	V	V <sub>GE</sub> = 0 V
Gate-emitter voltage	V <sub>GES</sub>	±17	V	V <sub>CE</sub> = 0 V, Refer to item 4 under Notes on the Actual Specifications
Collector current (Pulse)	I <sub>CM</sub>	300	А	$C_M = 2000 \mu F$ (see performance curve)
Maximum power dissipation	Pc	45	W	
Junction temperature	Tj	- 40 to +150	°C	
Storage temperature	Tstg	- 40 to +150	°C	
Mass	_	1.5	g	Typical value

## **Electrical Characteristics**

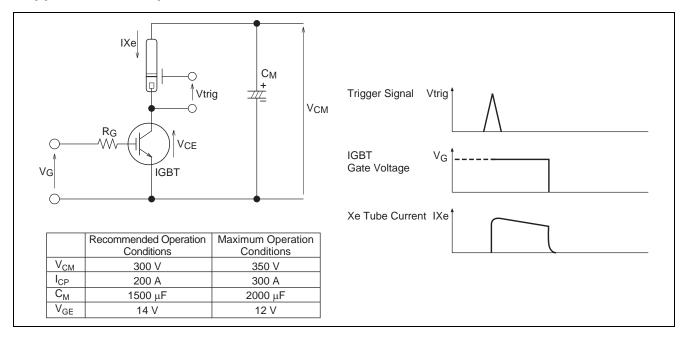
 $(Tj = 25^{\circ}C)$ 

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
Collector-emitter breakdown voltage	V <sub>(BR)CES</sub>	500	_	_	V	$I_C = 100 \mu A, V_{GE} = 0 V$
Collector-emitter leakage current	I <sub>CES</sub>	_	_	10	μΑ	$V_{CE} = 500 \text{ V}, V_{GE} = 0 \text{ V}$
Gate-emitter leakage current	I <sub>GES</sub>	_	_	±0.1	μΑ	$V_{GE} = \pm 17 \text{ V}, V_{CE} = 0 \text{ V}$
Gate-emitter threshold voltage	$V_{GE(th)}$	1.3	_	2.7	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	_	4.7	10	V	$I_C = 300 \text{ A}, V_{GE} = 12 \text{ V}$
Input capacitance	Ciss		2050	_	pF	V <sub>CE</sub> = 25 V
Output capacitance	Coss	_	130	_	pF	$V_{GE} = 0 V$
Reverse transfer capacitance	Crss	_	12	_	pF	f = 1 MHz
Turn-on delay time	t <sub>d(on)</sub>	_	0.10	_	μS	I <sub>C</sub> = 300 A
Rise time	t <sub>r</sub>	_	0.43	_	μS	V <sub>GE</sub> = 12 V
Turn-off delay time	t <sub>d(off)</sub>	_	0.20	_	μS	V <sub>CC</sub> = 300 V
Fall time	t <sub>f</sub>	_	0.55	_	μS	$R_G = 30 \Omega$

#### **Performance Curves**



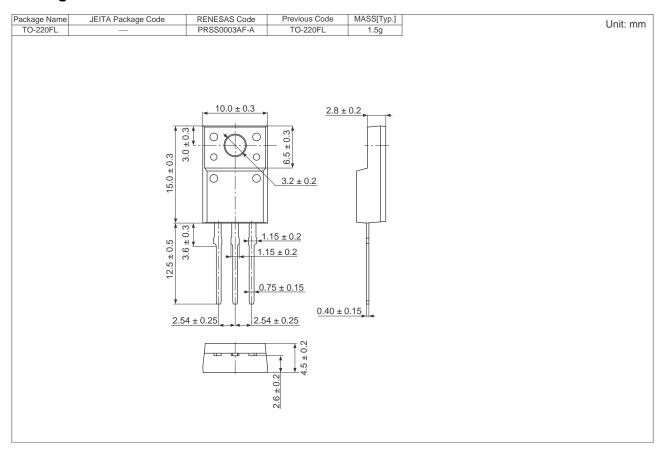
### **Application Example**



#### **Precautions on Usage**

- 1. Gate drive voltage during on-period must be applied to satisfy the rating of maximum pulse collector current. And turn-off dv/dt must become less than  $1000~V/\mu s$ .
- 2. IGBT has MOS structure and its gate is insulated by thin silicon oxide. So please handle carefully to protect the device from electrostatic charge.
- 3. The operation life should be endured until repeated discharge of 5,000 times under the charge current ( $I_{Xe} \le 300~A$ : full luminescence condition) of main capacitor. Repetition period under full luminescence condition is over 5 seconds
- 4. Total operation hours applied to the gate-emitter voltage must be within 5,000 hours.
- 5. Switching frequency is using it by less than 70 kHz.

## **Package Dimensions**



## **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJP5001APP-M0-T2	50 pcs	Magazine (Tube)

Note: The symbol of 2nd "-" is occasionally presented as "#".

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